

# High Current Density Surface-Mount TMBS® (Trench MOS Barrier Schottky) Rectifier

 Ultra Low  $V_F = 0.51$  V at  $I_F = 1.5$  A


## FEATURES

- Very low profile - typical height of 1.3 mm
- Trench MOS Schottky technology
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available  
- Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)

 AUTOMOTIVE  
GRADE  
Available

**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

## LINKS TO ADDITIONAL RESOURCES



## TYPICAL APPLICATIONS

For use in low voltage high frequency DC/DC converters, freewheeling diodes, and polarity protection applications.

## MECHANICAL DATA

**Case:** SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

### PRIMARY CHARACTERISTICS

|  |                     |
|--|---------------------|
| $I_{F(AV)}$                            | 2 x 3 A             |
| $V_{RRM}$                              | 120 V               |
| $I_{FSM}$                              | 70 A                |
| $V_F$ at $I_F = 3$ A ( $T_J = 125$ °C) | 0.6 V               |
| $T_J$ max.                             | 150 °C              |
| Package                                | SlimDPAK (TO-252AE) |
| Circuit configuration                  | Common cathode      |

### MAXIMUM RATINGS ( $T_A = 25$ °C unless otherwise noted)

| PARAMETER  | SYMBOL                     | V6PW12C     | UNIT |
|--|----------------------------|-------------|------|
| Device marking code  |                            | V6PW12C     |      |
| Maximum repetitive peak reverse voltage  | $V_{RRM}$                  | 120         | V    |
| Maximum average forward rectified current (Fig. 1)   | $I_{F(AV)}$ <sup>(1)</sup> | per device  | 6    |
|  |                            | per diode   | 3    |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | $I_{FSM}$                  | 70          | A    |
| Operating junction temperature range   | $T_J$ <sup>(2)</sup>       | -40 to +150 | °C   |
| Storage temperature range  | $T_{STG}$                  | -55 to +150 | °C   |

### Notes

<sup>(1)</sup> With infinite heatsink

<sup>(2)</sup> The heat generated must be less than the thermal conductivity from junction to ambient:  $dP_D/dT_J < 1/R_{\theta JA}$



| <b>ELECTRICAL CHARACTERISTICS</b> ( $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted) |                      |                                   |             |       |      |      |
|--|----------------------|-----------------------------------|-------------|-------|------|------|
| PARAMETER  | TEST CONDITIONS      |                                   | SYMBOL      | TYP.  | MAX. | UNIT |
| Instantaneous forward voltage per diode  | $I_F = 1.5\text{ A}$ | $T_J = 25\text{ }^\circ\text{C}$  | $V_F^{(1)}$ | 0.58  | -    | V    |
|  | $I_F = 3\text{ A}$   |                                   |             | 0.73  | 0.8  |      |
|  | $I_F = 1.5\text{ A}$ | $T_J = 125\text{ }^\circ\text{C}$ |             | 0.51  | -    |      |
|  | $I_F = 3\text{ A}$   |                                   |             | 0.6   | 0.68 |      |
| Reverse current per diode  | $V_R = 90\text{ V}$  | $T_J = 25\text{ }^\circ\text{C}$  | $I_R^{(2)}$ | 0.001 | -    | mA   |
|  |                      | $T_J = 125\text{ }^\circ\text{C}$ |             | 1.25  | -    |      |
|  | $V_R = 120\text{ V}$ | $T_J = 25\text{ }^\circ\text{C}$  |             | -     | 0.1  |      |
|  |                      | $T_J = 125\text{ }^\circ\text{C}$ |             | 2.5   | 7    |      |
| Typical junction capacitance per diode   | 4.0 V, 1 MHz         |                                   | $C_J$       | 280   | -    | pF   |

**Notes**

- (1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle  
(2) Pulse test: pulse width  $\leq 5\text{ ms}$

| <b>THERMAL CHARACTERISTICS</b> ( $T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted) |                          |         |                    |
|---|--------------------------|---------|--------------------|
| PARAMETER   | SYMBOL                   | V6PW12C | UNIT               |
| Typical thermal resistance per device   | $R_{\theta JA}^{(1)(2)}$ | 65      | $^\circ\text{C/W}$ |
|   | $R_{\theta JM}^{(3)}$    | 2.5     |                    |

**Notes**

- (1) The heat generated must be less than thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$   
(2) Free air, mounted on recommended copper pad area; thermal resistance  $R_{\theta JA}$  - junction to ambient  
(3) Mounted on infinite heat sink; thermal resistance  $R_{\theta JM}$  - junction-to-mount

| <b>ORDERING INFORMATION</b> (Example) |                 |                        |               |                                    |
|---------------------------------------|-----------------|------------------------|---------------|------------------------------------|
| PREFERRED P/N                         | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE                      |
| V6PW12C-M3/I                          | 0.20            | I                      | 4500          | 13" diameter plastic tape and reel |
| V6PW12CHM3/I <sup>(1)</sup>           | 0.20            | I                      | 4500          | 13" diameter plastic tape and reel |

**Note**

- (1) AEC-Q101 qualified

**RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25\text{ }^\circ\text{C}$  unless otherwise noted)

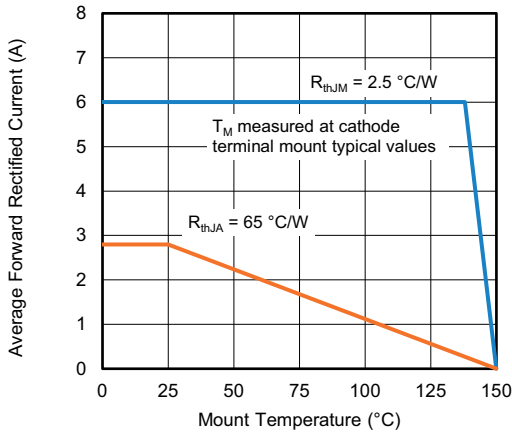


Fig. 1 - Maximum Forward Current Derating Curve

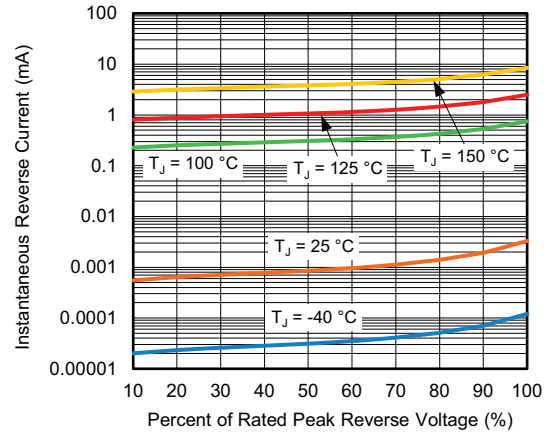


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

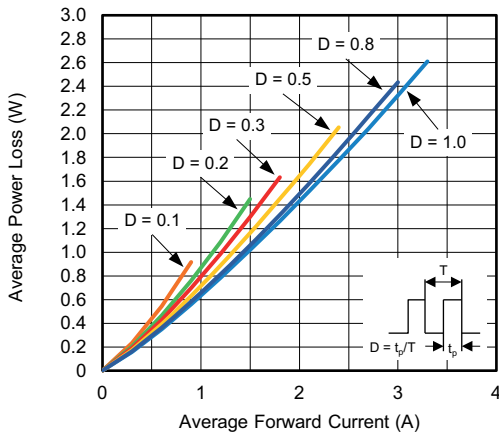


Fig. 2 - Forward Power Loss Characteristics Per Diode

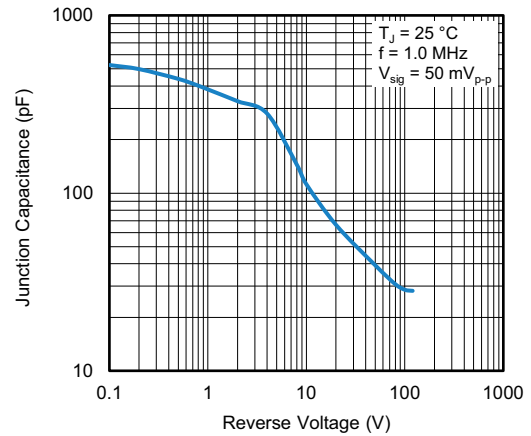


Fig. 5 - Typical Junction Capacitance Per Diode

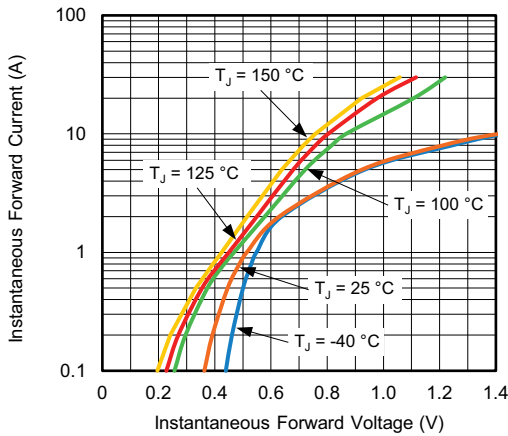


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

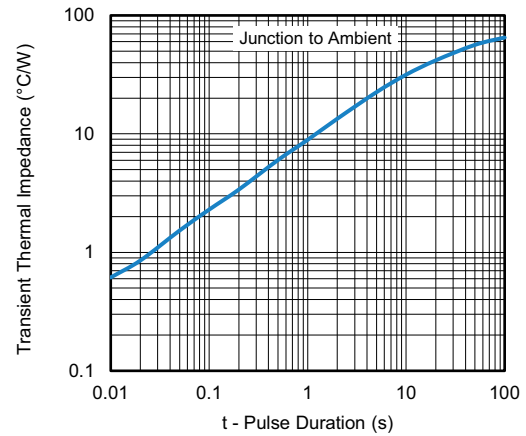


Fig. 6 - Typical Transient Thermal Impedance

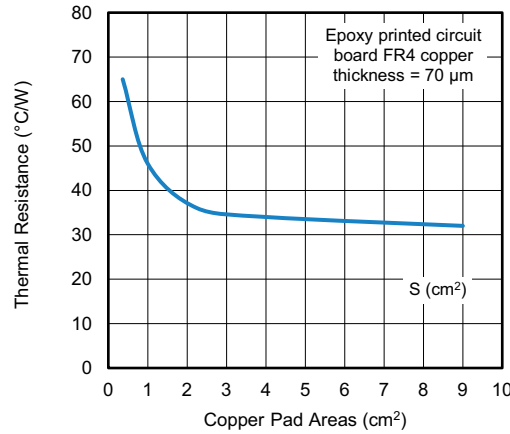
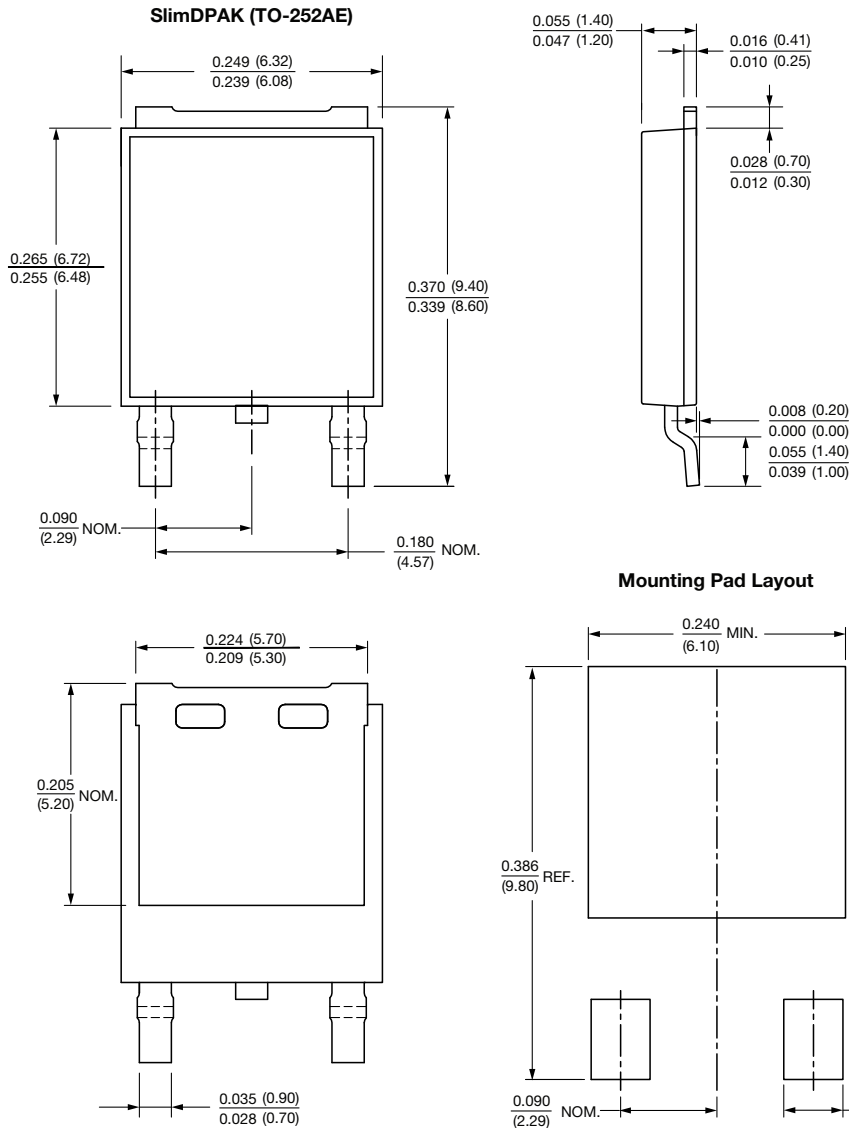


Fig. 7 - Typical Resistance Junction to Ambient vs. Copper Pad Areas

**PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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